EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	34	(hemt or high near2 electron near2 transistor) and (mbe or molecular near beam near2 epitax\$6) and inp near5 etch\$5 near2 stop\$5	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 14:19
L2	1	"20030141518".pn. and heterojunction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 16:12
L3	10	(hemt or high near2 electron near2 transistor) and (mbe or molecular near beam near2 epitax\$6) and inp near5 etch\$5 near2 stop\$5 and (beam or flux) near15 (inp)	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OS	2010/02/11 16:42
L4	16	1 and (InAIAs or InGaAs) near15 etch near2 stop\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 18:39
L6	1	"20030141518".pn. and etch\$4 near2 stop \$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 18:40
L5	О	"20030141518".pn. and etch near2 stop\$6	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 18:40

L8	28	(hemt or high near2 electron near2 transistor) and (mbe or molecular near beam near2 epitax\$6) and (inalasl or ingaas!) near5 etch\$5 near2 stop\$5 and @pye "2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11
L7	36	(hemt or high near2 electron near2 transistor) and (mbe or molecular near beam near2 epitax\$6) and (inalasl or ingaas!) near5 etch\$5 near2 stop\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 18:42
L9	6	(hemt or high near2 electron near2 transistor) near15 (inp or ingap) and (mbe or molecular near beam near2 epitax%6) and (inalasl or ingaasl) near6 etch\$6 near2 stop\$5 and @py<"2005"	US-PCPUB; USPAT; EPO; JPO; DEFWENT; IBM_TDB	OR	ON	2010/02/11 18:45
L11	1 7	(hemt or high near2 electron near2 transistor) same (inp or ingap) and (mbe or molecular near beam near2 epitax\$6) and (inalas! or ingaas!) near5 etch\$5 near2 stop\$5	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 18:56
L10	11	(hemt or high near2 electron near2 transistor) same (inp or ingap) and (mbe or molecular near beam near2 epitax\$\fo\$\$ is on d (inalas! or ingaas!) near5 etch\$\$ near2 stop\$\$ and @py<"2005"	US-PCPUB; USPAT; EPO; JPO; DEFWENT; IBM_TDB	OR	ON	2010/02/11 18:56

L12	37	electron near2 transistor) same (inp or ingap) and (inalas!	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 19:05
L13	10	(hemt or high near2 electron near2 transistor) same (inp or ingap) same (inalas! or ingaas!) near5 etch\$5 near2 stop\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 19:06
L14	7	(hemt or high near2 electron near2 transistor) same (inp or ingap) same (ingaast) near5 etch\$5 near2 stop\$5	US-PCPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 21:03
L15	69	(ANAMI near2 TAKAYOSHI or NANBAE near2 KOICHI).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/02/11 22:58

EAST Search History (Interference)

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2/11/10 11:01:29 PM H:\ EAST\ 10563105.wsp